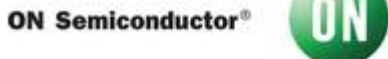
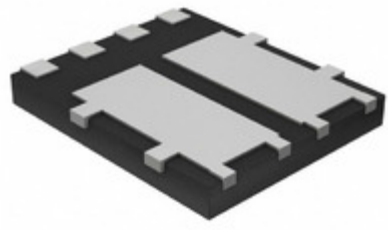



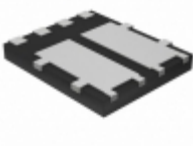
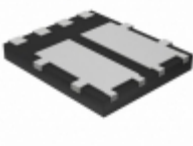
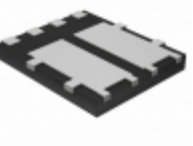
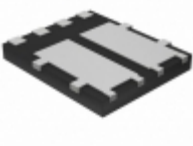
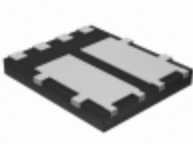
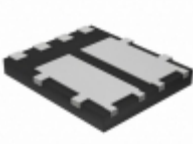
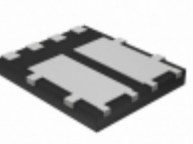
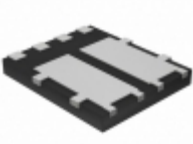
| | |
|---|---|
|  | <h2 style="color: red;">NVMFD5873NLT1G</h2> |
|  | Hersteller-Teilenummer: NVMFD5873NLT1G |
| | Hersteller / Marke: AMI Semiconductor / ON Semiconductor |
| | Teil der Beschreibung: MOSFET 2N-CH 60V 10A SO8FL |
| | Datenblätter:  NVMFD5873NLT1G.pdf |
| | RoHs Status: Bleifrei / RoHS-konform |
| | Lagerzustand: New original, 219 pcs Stock Available. |
| Liefern von: Hong Kong | |
| Versandweg: DHL/Fedex/TNT/UPS/EMS | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|--|
| Teilenummer | NVMFD5873NLT1G |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET 2N-CH 60V 10A SO8FL |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 219 pcs Stock |
| VGS (th) (Max) @ Id | 2.5V @ 250µA |
| Supplier Device-Gehäuse | 8-DFN (5x6) Dual Flag (SO8FL-Dual-Asymmetrical) |
| Serie | - |
| Rds On (Max) @ Id, Vgs | 13 mOhm @ 15A, 10V |
| Leistung - max | 3.1W |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | 8-PowerTDFN |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Eingabekapazität (Ciss) (Max) @ Vds | 1560pF @ 25V |
| Gate Charge (Qg) (Max) @ Vgs | 30.5nC @ 10V |
| Typ FET | 2 N-Channel (Dual) |
| FET-Merkmal | Logic Level Gate |
| Drain-Source-Spannung (Vdss) | 60V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 10A |

NVMFD5873NLT1G Electronic Components ist ein 100% neues Original von YIC Distributor, NVMFD5873NLT1G-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, NVMFD5873NLT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.
RFQ NVMFD5873NLT1G E-Mail: Info@Y-IC.com

Sie können auch interessiert

| | | | |
|---|--|--|---|
| <p>sein:</p>  <p>NVMFD5853NLWFT1G ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p> |  <p>NVMFD5853NLT1G ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p> |  <p>NVMFD5853NT1G ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p> |  <p>NVMFD5853NWFT1G ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p> |
|  <p>NVMFD5875NLWFT1G ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p> |  <p>NVMFD5873NLWFT1G ON Semiconductor MOSFET 2N-CH 60V 10A SO8FL</p> |  <p>NVMFD5875NLT3G ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p> |  <p>NVMFD5875NLT1G ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p> |

Verwandtes Hot-Keyword

Mehr

| | | | | |
|---|----------------------------|-----------------------------|----------------------|---|
| NVMFD5873NLT1G AMI Semiconductor / ON Semiconductor | NVMFD5873NLT1G Datenblatt | NVMFD5873NLT1G-Datenblätter | NVMFD5873NLT1G PDF | AMI Semiconductor / ON Semiconductor NVMFD5873NLT1G |
| NVMFD5873NLT1G Electronic | NVMFD5873NLT1G-Komponenten | NVMFD5873NLT1G-Verteiler | NVMFD5873NLT1G-Bild | NVMFD5873NLT1G-Teil |
| NVMFD5873NLT1G Preis | NVMFD5873NLT1G Hersteller | NVMFD5873NLT1G Bild | NVMFD5873NLT1G Aktie | NVMFD5873NLT1G Inventar |
| NVMFD5873NLT1G Neu | NVMFD5873NLT1G Original | NVMFD5873NLT1G garantiert | NVMFD5873NLT1G RFQ | NVMFD5873NLT1G Online bestellen |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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